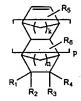
## Amendments to the Claims:

This listing of claims will replace all prior versions, and listings of claims in the application:

## **Listing of Claims:**

- 1. (Currently amended) A photoresist copolymer derived from a mixture of monomers comprising consisting essentially of:
  - (a) two or more alicyclic olefin derivatives, each having the formula: <Chemical Formula 4>



wherein

k and n is independently 1 or 2;

p is an integer from 0 to 5;

R<sub>5</sub> and R<sub>6</sub> are independently hydrogen or methyl; and

 $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  individually represent hydrogen, straight or branched  $C_{1-10}$  alkyl, straight or branched  $C_{1-10}$  ester, straight or branched  $C_{1-10}$  ketone, straight or branched  $C_{1-10}$  acetal, straight or branched  $C_{1-10}$  alkyl including at least one hydroxyl group, straight or branched  $C_{1-10}$  ester including at least one hydroxyl group, straight or branched  $C_{1-10}$  ketone including at least one hydroxyl group, straight or branched  $C_{1-10}$  carboxylic acid including at least one hydroxyl group, and straight or branched  $C_{1-10}$  acetal including at least one hydroxyl group,

wherein, all of  $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  do not represent hydrogen at the same time and at least one of  $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  represent straight or branched  $C_{1-10}$  ester including at least one hydroxyl group, straight or branched  $C_{1-10}$  ketone including at least one hydroxyl group, straight or branched  $C_{1-10}$  carboxylic group including at least one hydroxyl group, straight or branched  $C_{1-10}$  acetal including at least one hydroxyl group; and

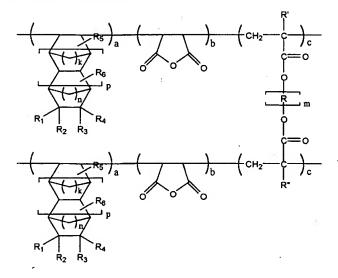
(b) a cross-linking monomer of the formula:

wherein

each of R' and R" is independently hydrogen or methyl; m is an integer from 1 to 10; and

R is straight or branched  $C_{1-10}$  alkyl, optionally comprising an ester, a ketone, a carboxylic acid, an acetal, a hydroxyl group or a combination thereof; and

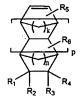
- (c) maleic anhydride.
- 2. (Canceled).
- (Original) The photoresist copolymer according to claim 1 of the formula:< Chemical Formula 5>



## wherein

k, m, n, p, R,  $R_1$ ,  $R_2$ ,  $R_3$ ,  $R_4$ ,  $R_5$ ,  $R_6$ , R', and R'' are those defined in Claim 1; and the ratio a: b: c is 1-50 mol%: 10-50 mol%: 0.1-20 mol%.

- 4. (Previously presented) The photoresist polymer comprising poly(maleic anhydride / 2-hydroxyethyl 5-norbornene-2-carboxylate / tert-butyl 5-norbornene-2-carboxylate / 5-norbornene-2-carboxylic acid / 1,3-butanediol diacrylate); or poly(maleic anhydride / 2-hydroxyethyl 5-norbornene-2-carboxylate / tert-butyl 5-norbornene-2-carboxylate / 5-norbornene-2-carboxylic acid / 1,4-butanediol diacrylate).
- 5. (Currently amended) A process for preparing a photoresist copolymer comprising admixing a mixture comprising consisting essentially of at least two alicyclic monomers, a cross-linking monomer, maleic anhydride and a polymerization initiator under polymerization reaction conditions sufficient to produce the photoresist copolymer, wherein each alicyclic monomer is of the formula:



wherein

k and n is independently 1 or 2;

p is an integer from 0 to 5;

 $R_5$  and  $R_6$  are independently hydrogen or methyl; and

 $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  individually represent hydrogen, straight or branched  $C_{1\text{-}10}$  alkyl, straight or branched  $C_{1\text{-}10}$  ester, straight or branched  $C_{1\text{-}10}$  ketone, straight or branched  $C_{1\text{-}10}$  acetal, straight or branched  $C_{1\text{-}10}$  alkyl including at least one hydroxyl group, straight or branched  $C_{1\text{-}10}$  ester including at least one hydroxyl group, straight or branched  $C_{1\text{-}10}$  ketone including at least one hydroxyl group, straight or branched  $C_{1\text{-}10}$  carboxylic acid including at least one hydroxyl group, and straight or branched  $C_{1\text{-}10}$  acetal

including at least one hydroxyl group, wherein, all of  $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  do not represent hydrogen at the same time and at least one of  $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$  represent straight or branched  $C_{1-10}$  ester-including at least one hydroxyl group, straight or branched  $C_{1-10}$  ketone including at least one hydroxyl group, straight or branched  $C_{1-10}$  carboxylic group including at least one hydroxyl group, straight or branched  $C_{1-10}$  acetal including at least one hydroxyl group;

and the cross-linking monomer is of the formula:

wherein

each of R' and R" is independently hydrogen or methyl; m is an integer from 1 to 10; and

R is straight or branched  $C_{1-10}$  alkyl, optionally comprising an ester, a ketone, a carboxylic acid, an acetal, a hydroxyl group or a combination thereof.

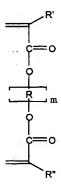
- 6. (Original) The process for preparing a photoresist copolymer according to claim 5, wherein the polymerization reaction is carried out under an atmosphere of nitrogen or argon.
- 7. (Original) The process for preparing a photoresist copolymer according to claim 5, wherein the polymerization reaction is carried out at a temperature between 60°C and 130°C.
- 8. (Original) The process for preparing a photoresist copolymer according to claim 5, wherein the polymerization reaction is carried out under the pressure between 0.0001 and 5 atm.

- 9. (Previously presented) The process for preparing a photoresist copolymer according to claim 5, wherein the mixture is dissolved in an organic solvent selected from the group consisting of cyclohexanone, methyl ethyl ketone, benzene, toluene, dioxane, tetrahydrofuran, propylene glycol methyl ether acetate, dimethylformamide, and a mixture thereof.
- 10. (Original) The process for preparing a photoresist copolymer according to claim 5, wherein the polymerization initiator is one or more compound(s) selected from the group consisting of 2,2-azobisisobutyronitrile (AIBN), acetyl peroxide, lauryl peroxide, tertbutyl peracetate, tert-butyl hydroperacetate and tert-butyl peroxide.
- 11. (Original) The photoresist composition comprising (i) a photoresist copolymer according to claim 1, and (ii) an organic solvent.
- 12. (Original) The photoresist composition according to claim 11, which further comprises a photoacid generator.
- 13. (Original) The photoresist composition according to claim 12, wherein the photoacid generator is one or more compound(s) selected from the group consisting of diphenyl iodide hexafluorophosphate, diphenyl iodide hexafluoroarsenate, diphenyl iodide hexafluoroantimonate, diphenyl p-methoxyphenyl triflate, diphenyl p-toluenyl triflate, diphenyl p-isobutylphenyl triflate, diphenyl p-tert-butylphenyl triflate, triphenylsulfonium hexafluorophosphate, triphenylsulfonium hexafluoroarsenate, triphenylsulfonium triflate.
- 14. (Original) A process for forming a photoresist pattern, which comprises the steps of (a) coating a photoresist composition according to claim 11 on a wafer, (b) exposing the wafer to patterned light by employing an exposer, and (c) developing the exposed wafer.
- 15. (Original) The process for forming a photoresist pattern according to claim 14, wherein the step (b) is carried out by using a light source selected from the group consisting of ArF, KrF, E-beam, X-ray, EUV (extremely ultraviolet) and DUV (deep ultraviolet).

- 16. (Original) The process according to claim 15, which further comprises baking step(s) before and/or after step (b).
- 17. (Original) The process according to claim 16, wherein the baking step(s) are performed at a temperature of 50°C to 200°C.
- 18. (Original) The process according to claim 14, wherein the developing step (c) is carried out using an aqueous solution of TMAH (tetramethylamine hydroxide).
- 19. (Original) A semiconductor element manufactured by using a process according to claim 14.

## 20. - 21.(Canceled)

- 22. (New) The photoresist copolymer according to claim 1 wherein said mixture of monomers further comprises maleic anhydride.
- 23. (New) The process according to claim 5 wherein the mixture of monomers further comprises maleic anhydride.
- 24. (New) The photoresist copolymer according to claim 1 wherein the cross-linking monomer is 1,3-butanediol diacrylate or 1,4-butanediol diacrylate.
- 25. (New) A photoresist copolymer comprising the polymerization product of two or more alicyclic olefin derivatives and a cross-linking monomer of the formula:



wherein

each of R' and R" is independently hydrogen or methyl; m is an integer from 1 to 10; and

R is straight or branched  $C_{1-10}$  alkyl, optionally comprising an ester, a ketone, a carboxylic acid, an acetal, a hydroxyl group or a combination thereof.